■ MN101C54A , MN101C54C

Туре	MN101C54A	MN101C54C			
ROM (x8-bit)	32 K	48 K			
RAM (×8-bit)	2 K	2 K			
Package	QFP084-P-1818E *Lead-free, LQFP080-P-1414A *Lead-free, TQFP080-P-1212D *Lead-free (under plan				
Minimum Instruction Execution Time	0.1 μs (at 4.5 V to 5.5 V, 20 MHz) 0.25 μs (at 2.7 V to 5.5 V, 8 MHz)*1 62.5 μs (at 2.0 V to 5.5 V, 32 kHz)*1,2 *1 The lower limit for operation guarantee for flash memory built-in type is 4.5 V. *2 The lower limit for operation guarantee for EPROM built-in type is 2.3 V.				
Interrupts	• RESET • Watchdog • External 0 • External 1 • External 2 • External 3*1 • External 4 (key interrupt dedicated) • Timer 0 • Timer 1 • Timer 2 • Timer 3 • Timer 6 • Time base • Timer 7 (2 systems) • Timer 8 (2 systems) • Serial 0 (2 systems) • Serial 2 • A/D conversion finish * LQFP080-P-1414A, TQFP080-P-1212D: Not mounted				
Timer Counter	Timer counter 0: 8-bit × 1 (square-wave/8-bit PWM output, event count, generation of remote control carrier, simple pulse width measurement) (square-wave/PWM output to large current terminal P50 possible) Clock source				
	Timer counter 1: 8-bit × 1 (square-wave output, event count, synchronous output event) Clock source				
	Interrupt source coincidence with compare register 1 Timer counter 0, 1 can be cascade-connected.				
	Timer counter 2: 8-bit × 1 (square-wave output, additional pulse type 10-bit PV simple pulse width measurement) (square-wave/PW Clock source	M output to large current terminal P52 possible) clock frequency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillation of XI oscillation clock frequency; external clock input			
	•	clock frequency; 1/1, 1/4, 1/16, 1/64, 1/128 of OSC oscillation of XI oscillation clock frequency; external clock input			
	Timer counter 2, 3 can be cascade-connected.				
	•	r frequency; 1/1, 1/4096, 1/8192 of OSC oscillation clock 096, 1/8192 of XI oscillation clock frequency ompare register 6			
	output evevt, pulse width measurement, input capt possible) Clock source	cle / duty continuous variable), event count, synchronous ure) (square-wave/PWM output to large current terminal P5 of system clock frequency; 1/1, 1/2, 1/4, 1/16 of OSC equency; 1/1, 1/2, 1/4, 1/16 of external clock input frequency			

Interrupt source ····· coincidence with compare register 7 (2 lines)

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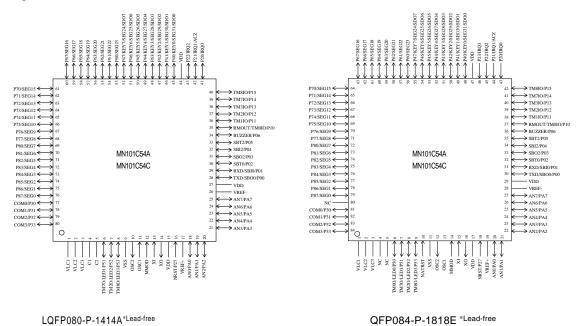
Timer Counter (Continue)		Timer counter 8: 16 bit × 1 (square-wave/16-bit PWM output [duty continuous variable], event count, pulse width measurement, input capture) (square-wave/PWM output to large current terminal P53 possible) Clock source							
					Serial Interface		Serial 0 : synchronous type/UART (full-duplex) × 1 Clock source ····································		
							Seria	1 2 : synchronous type × 1 Clock source	• • •
I/O Pins	I/O	61 (60)	Common use	put/output selectable (bit unit) (): LQFP080-P-1414A,TQFP080-P-1212I					
	Input	4 (3)	Common use	(): LQFP080-P-1414A,TQFP080-P-1212I					
A/D Inputs		10-b	it × 8-ch. (with S/H)						
LCD		LCD LCD	egments × 4 commons (static, 1/2, 1/3, or 1/4 duty) power supply separated from VDD (usable if VDD ≤ VLC power step-up circuit contained (3/2, 2 and 3 times) power shunt resistance contained	D ≤ 5.5 V)					
Special Ports	}	Buzzer output, remote control carrier signal output, high-current drive port							
Electrical Cha	aracteristics								

Electrical Characteristics

Supply current

Parameter	Symbol	Condition	Limit			Unit
Farameter	Symbol	Condition		typ	max	Oilit
	IDD1	fosc = 20 MHz, VDD = 5 V		25	60	mA
Operating supply current	IDD2	fosc = 8 MHz, VDD = 5 V		10	25	mA
	IDD3	fx = 32 kHz, VDD = 3 V		30	100	μА
Owner was a state	IDD4	fx = 32 kHz, VDD = 3 V, Ta = 25°C		4	8	μА
Supply current at HALT	IDD5	$fx = 32 \text{ kHz}, VDD = 3 \text{ V}, Ta = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			30	μА
0 1	IDD6	VDD = 5 V, Ta = 25°C			2	μА
Supply current at STOP	IDD7	$VDD = 5 \text{ V}, \text{ Ta} = -40^{\circ}\text{C to} + 85^{\circ}\text{C}$			50	μА

Pin Assignment



Support Tool

TQFP080-P-1212D *Lead-free (under planning)

n-circuit Emulator	mulator PX-ICE101C / D + PX-PRB101C54-TPFP080-P-1212D-M (under planning) PX-ICE101C / D + PX-PRB101C54-QFP084-P-1818E-M PX-ICE101C / D + PX-PRB101C54-LQFP080-P-1414A-M	
EPROM Built-in Type	Туре	MN101CP54C
	ROM (× 8-bit)	48 K
	RAM (× 8-bit)	2 K
	Minimum instruction execution time	0.1 μs (at 4.5 V to 5.5 V, 20 MHz)
		$0.25~\mu s$ (at $2.7~V$ to $5.5~V,~8~MHz)$
		62.5 µs (at 2.3 V to 5.5 V, 32 kHz)
	Package	LQFP080-P-1414A *Lead-free, QFP084-P-1818E *Lead-free,
		TQFP080-P-1212D *Lead-free (under planning)
Flash Memory Built-in Type	Туре	MN101CF54D [ES (Engineering Sample) available]
	ROM (× 8-bit)	64 K
	RAM (× 8-bit)	2 K
	Minimum instruction execution time	0.1 μs (at 4.5 V to 5.5 V, 20 MHz)
		$0.25~\mu s$ (at 4.5 V to 5.5 V, 8 MHz)
		62.5 µs (at 4.5 V to 5.5 V, 32 kHz)
	Package	LQFP080-P-1414A *Lead-free, QFP084-P-1818E *Lead-free,
		TQFP080-P-1212D *Lead-free (under planning)

MN101C54A, MN101C54C □

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